



JIANGSU CHANGJIANG ELECTRONICS TECHNOLOGY CO.,LTD

## WBFBP-03B Plastic-Encapsulate Transistors

### S9013M TRANSISTOR

#### DESCRIPTION

NPN Epitaxial Silicon Transistor

#### FEATURES

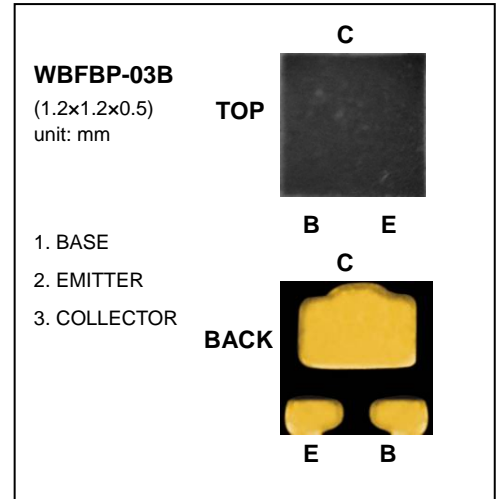
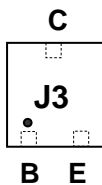
- High Collector Current. ( $I_C=500\text{mA}$ )
- Complementary to S9012M
- Excellent  $h_{FE}$  linearity.

#### APPLICATION

150mW Output Amplifier of Potable Radios in Class B Push-pull Operation.

For portable equipment:(i.e. Mobile phone,MP3, MD,CD-ROM, DVD-ROM,Note book PC, etc.)

#### MARKING: J3



#### MAXIMUM RATINGS $T_A=25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Value	Units
$V_{CBO}$	Collector-Base Voltage	40	V
$V_{CEO}$	Collector-Emitter Voltage	25	V
$V_{EBO}$	Emitter-Base Voltage	5	V
$I_C$	Collector Current -Continuous	500	mA
$P_C$	Collector Dissipation	150	mW
$T_J$	Junction Temperature	150	$^\circ\text{C}$
$T_{stg}$	Storage Temperature	-55-150	$^\circ\text{C}$

#### ELECTRICAL CHARACTERISTICS( $T_{amb}=25^\circ\text{C}$ unless otherwise specified)

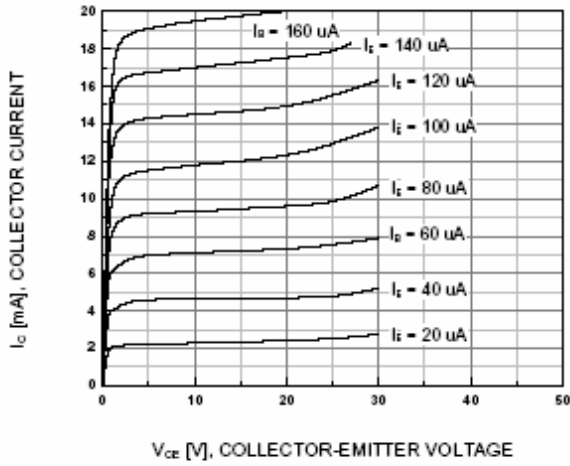
Parameter	Symbol	Test conditions	MIN	TYP	MAX	UNIT
Collector-base breakdown voltage	$V_{(BR)CBO}$	$I_C=100\mu\text{A}, I_E=0$	40			V
Collector-emitter breakdown voltage	$V_{(BR)CEO}$	$I_C=1\text{mA}, I_B=0$	25			V
Emitter-base breakdown voltage	$V_{(BR)EBO}$	$I_E=100\mu\text{A}, I_C=0$	5			V
Collector cut-off current	$I_{CBO}$	$V_{CB}=40\text{V}, I_E=0$			0.1	$\mu\text{A}$
Collector cut-off current	$I_{CEO}$	$V_{CE}=20\text{V}, I_B=0$			0.1	$\mu\text{A}$
Emitter cut-off current	$I_{EBO}$	$V_{EB}=5\text{V}, I_C=0$			0.1	$\mu\text{A}$
DC current gain	$h_{FE1}$	$V_{CE}=1\text{V}, I_C=50\text{mA}$	120		400	
	$h_{FE2}$	$V_{CE}=1\text{V}, I_C=500\text{mA}$	40			
Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_C=500\text{mA}, I_B=50\text{mA}$			0.6	V
Base-emitter saturation voltage	$V_{BE(sat)}$	$I_C=500\text{mA}, I_B=50\text{mA}$			1.2	V
Transition frequency	$f_T$	$V_{CE}=6\text{V}, I_C=20\text{mA}$ $f=30\text{MHz}$	150			MHz
Collector output capacitance	$C_{ob}$	$V_{CB}=6\text{V}, I_E=0, f=1\text{MHz}$			8	pF

**CLASSIFICATION OF  $h_{FE1}$**

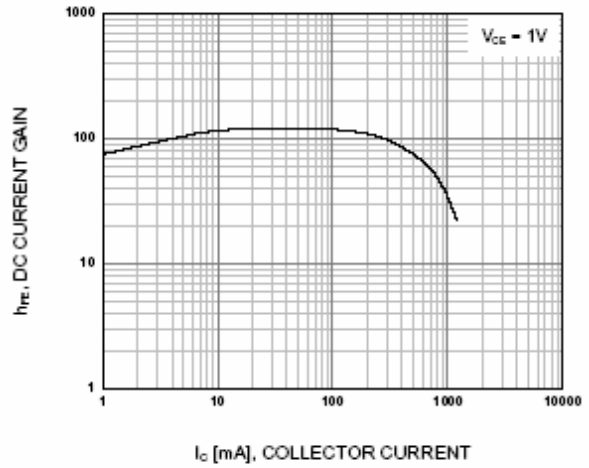
Rank	L	H	J
Range	120-200	200-350	300-400

**Typical Characteristics**

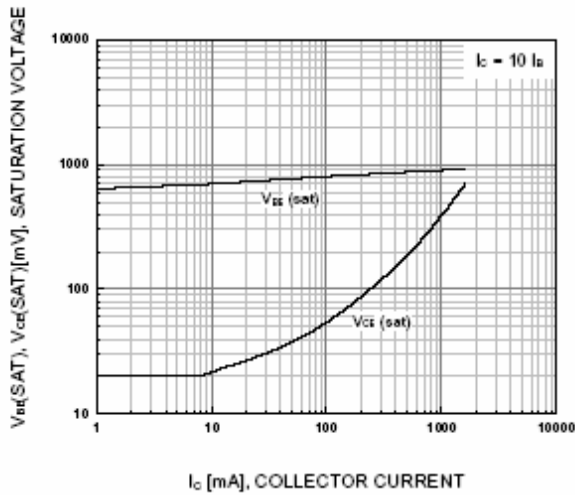
**S9013M**



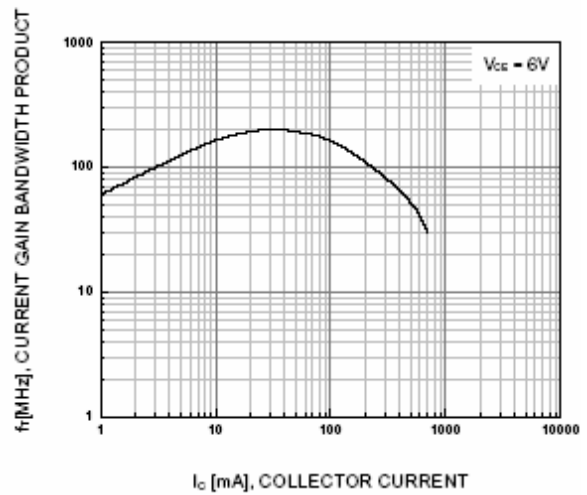
**Figure 1. Static Characteristic**



**Figure 2. DC current Gain**

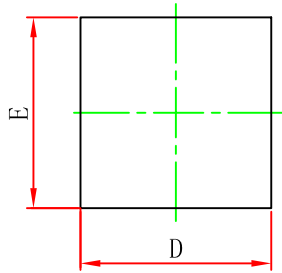


**Figure 3. Base-Emitter Saturation Voltage  
Collector-Emitter Saturation Voltage**

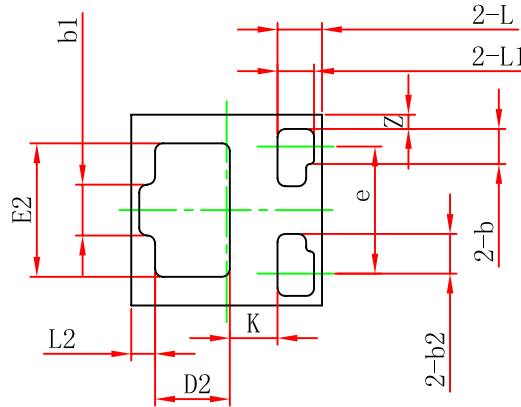


**Figure 4. Current Gain Bandwidth Product**

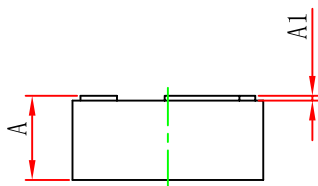
# WBFBP-03B(1.2×1.2×0.5) PACKAGE OUTLINE DIMENSIONS



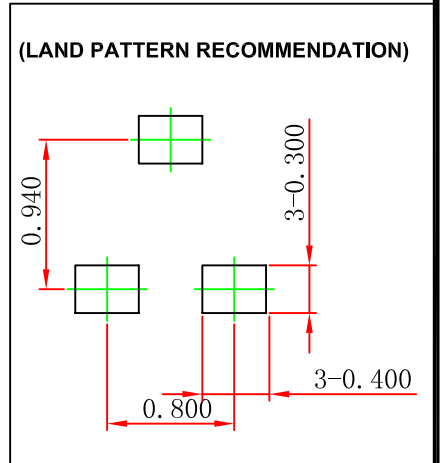
TOP VIEW



BOTTOM VIEW



SIDE VIEW



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	0.450	0.550	0.018	0.022
A1	0.010	0.090	0.000	0.004
b	0.170	0.270	0.007	0.011
b1	0.270	0.370	0.011	0.015
b2	0.250 REF.		0.010 REF.	
D	1.150	1.250	0.045	0.049
E	1.150	1.250	0.045	0.049
D2	0.470 REF.		0.002 REF.	
E2	0.810 REF.		0.032 REF.	
e	0.800 TYP.		0.032 TYP.	
L	0.280 REF.		0.011 REF.	
L1	0.230 REF.		0.009 REF.	
L2	0.150 REF.		0.006 REF.	
k	0.300 REF.		0.012 REF.	
z	0.090 REF.		0.004 REF.	